

General Description

The MY4N60D can be used in various power switching circuit for system miniaturization and higher efficiency.

The package form is TO-252-2L, which accords with the RoHS standard.

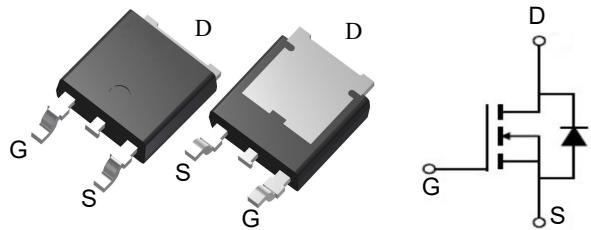


Features

V _{DSS}	600	V
I _D	4	A
P _D (T _C = 25 °C)	104	W
R _{DS(ON)} (at V _{GS} = 10V)	< 2.1	Ω

Application

- Power switch circuit
- Adaptor and charger



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MY4N60D	TO-252	MY4N60D	2500

Absolute Maximum Ratings (T_c=25 °C unless otherwise noted)

Symbol	Parameters	Ratings	Unit
V _{DSS}	Drain-Source Voltage	600	V
V _{GS}	Gate-Source Voltage-Continuous	±30	V
I _D	Drain Current-Continuous (Note 2)	4	A
I _{DM}	Drain Current-Single Plused (Note 1)	16	A
P _D	Power Dissipation (Note 2)	104	W
T _j	Max.Operating junction temperature	150	°C/W

Electrical Characteristics (T_c=25 °C, unless otherwise noted)

Symbol	Parameters	Min	Typ	Max	Units	Conditions
Static Characteristics						
B _{VDSS}	Drain-Source Breakdown VoltageCurrent (Note 1)	600	--	--	mA	I _D =250μA V _{GS} =0V , T _J =25°C
V _{GS(th)}	Gate Threshold Voltage	2.0	--	4.0	V	V _{DS} =V _{GS} , I _D =250μA
R _{DS(on)}	Drain-Source On-Resistance	--	--	2.1	Ω	V _{GS} =10V , I _D =2A
I _{GSS}	Gate-Body Leakage Current	--	--	±100	nA	V _{GS} =±30V , V _{DS} =0
I _{DS}	Zero Gate Voltage Drain Current	--	--	1	μA	V _{DS} =600V , V _{GS} =0
g _{fs}	Forward Transconductance	1.2	--	--	S	V _{DS} =15V, I _D =2A
Switching Characteristics						
T _{d (on)}	Turn-On Delay Time	--	20	40	ns	V _{DS} =300V , I _D =4A, R _G =25Ω (Note 2)
T _r	Rise Time	--	45	100	ns	
T _{d (off)}	Turn-Off Delay Time	--	35	70	ns	
T _f	Fall Time	--	35	85	ns	
Q _g	Total Gate Charge	--	20	35	nC	V _{DS} =480, V _{GS} =10V , I _D =4A (Note 2)
Q _{gs}	Gate-Source Charge	--	4.5	--	nC	
Q _{gd}	Gate-Drain Charge	--	7.5	--	nC	
Dynamic Characteristics						
C _{iss}	Input Capacitance	--	525	690	pF	V _{DS} =25V , V _{GS} =0, f=1MHz
C _{oss}	Output Capacitance	--	78	100	pF	
C _{rss}	Reverse Transfer Capacitance	--	8	22	pF	
I _s	Continuous Drain-Source Diode ForwardCurrent (Note 2)	--	--	4	A	
V _{SD}	Diode Forward On-Voltage	--	--	1.4	V	I _s =4A , V _{GS} =0
R _{th(j-c)}	Thermal Resistance, Junction to Case	--	--	1.2	°C/W	

Note 1: Repetitive Rating : Pulse width limited by maximum junction temperature

Note 2: Pulse test: PW <= 300us , duty cycle <= 2%.

Ratings and Characteristic curves

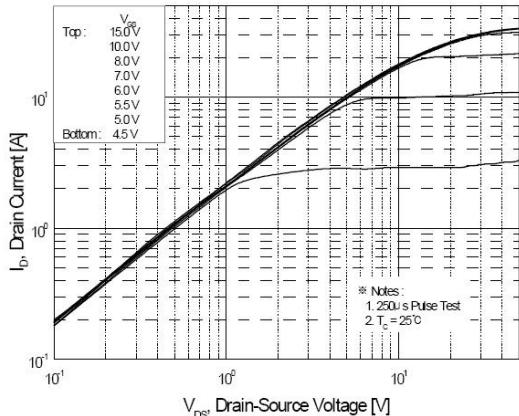


Figure 1. On-Region Characteristics

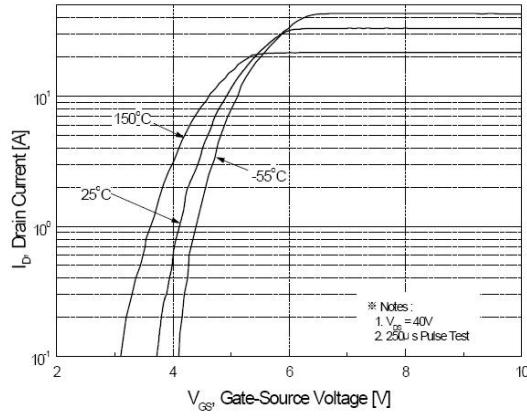


Figure 2. Transfer Characteristics

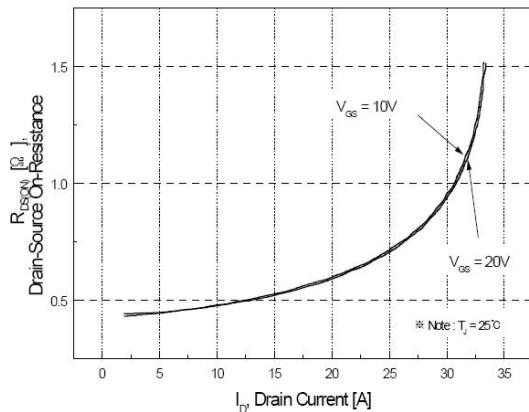


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

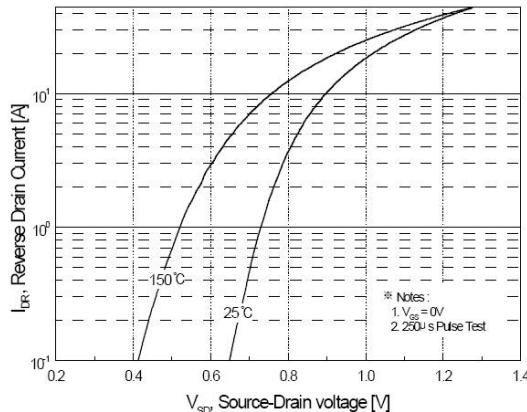


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

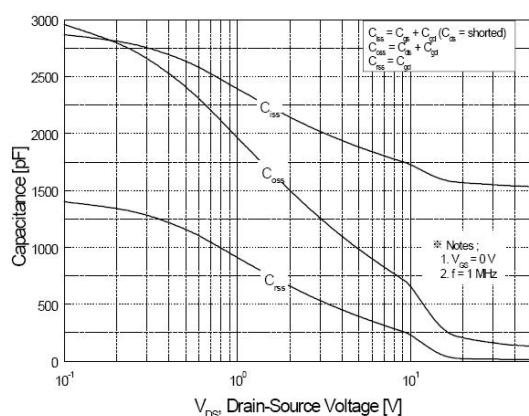


Figure 5. Capacitance Characteristics

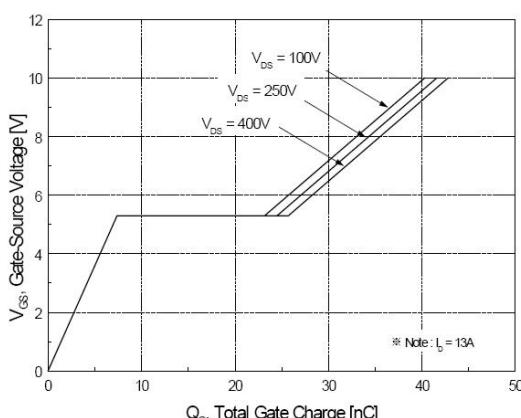
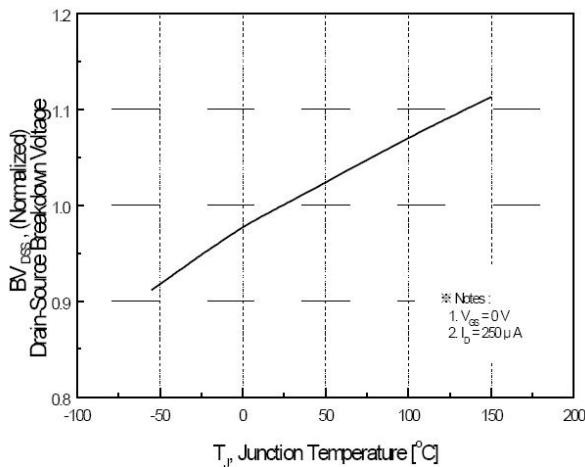
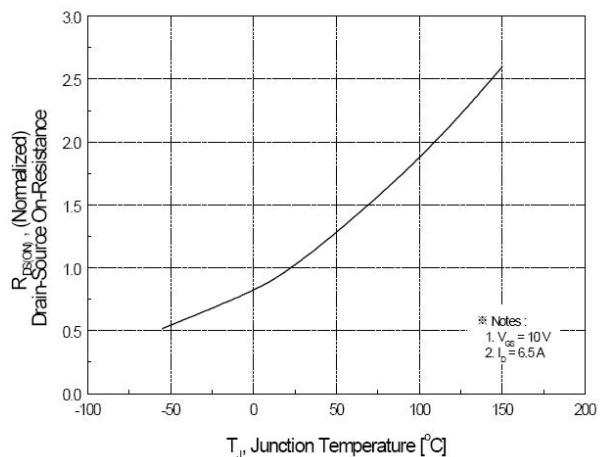


Figure 6. Gate Charge Characteristics



**Figure 7. Breakdown Voltage Variation
vs Temperature**



**Figure 8. On-Resistance Variation
vs Temperature**

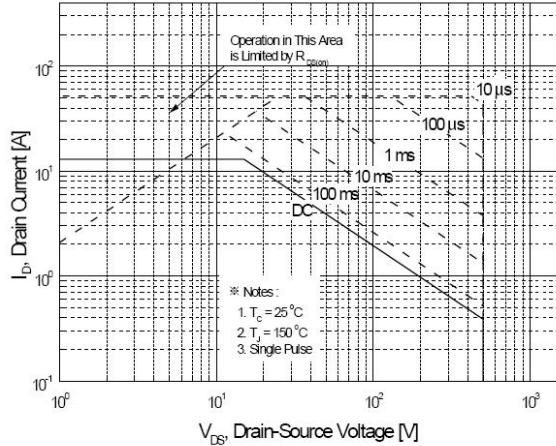
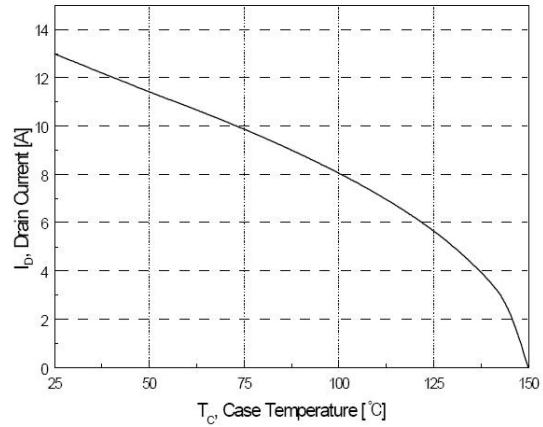


Figure 9. Maximum Safe Operating Area



**Figure 10. Maximum Drain Current
vs Case Temperature**

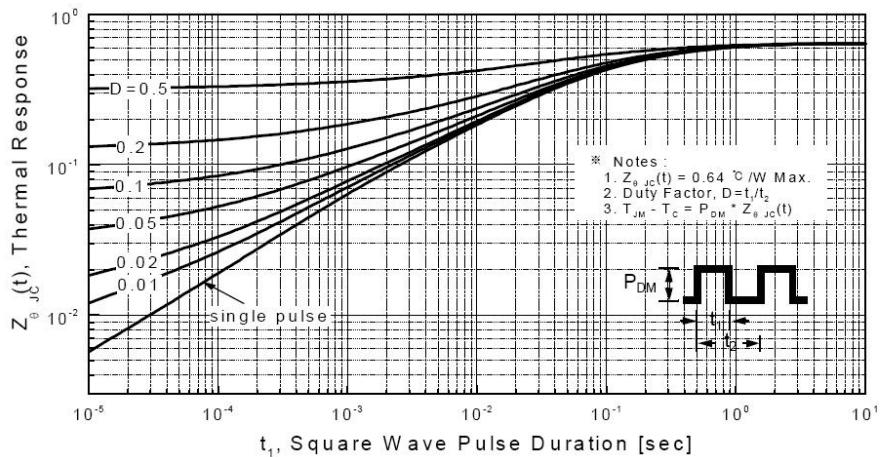


Figure 11. Transient Thermal Response Curve

Fig 12. Gate Charge Test Circuit & Waveform

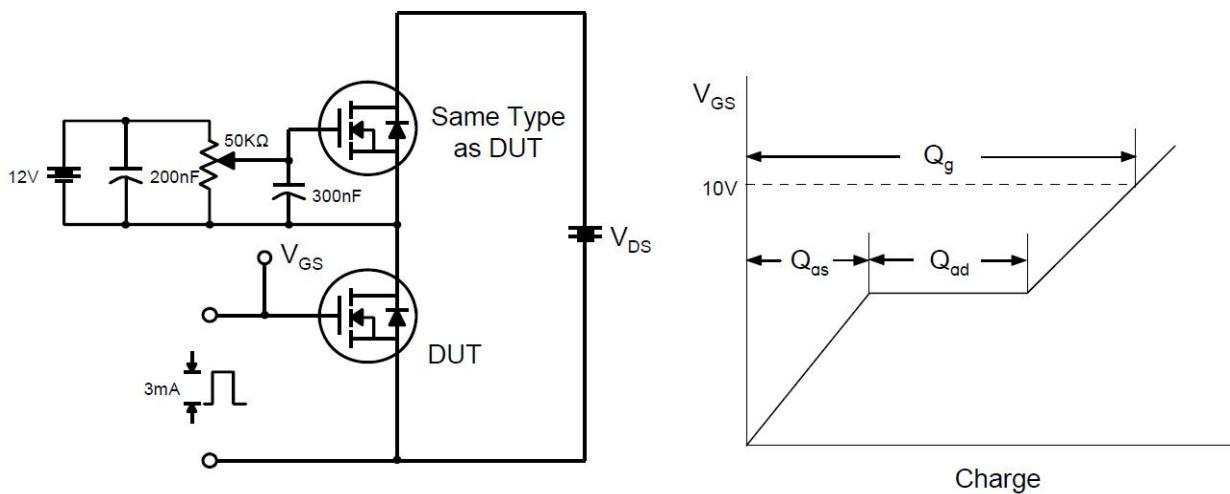


Fig 13. Resistive Switching Test Circuit & Waveforms

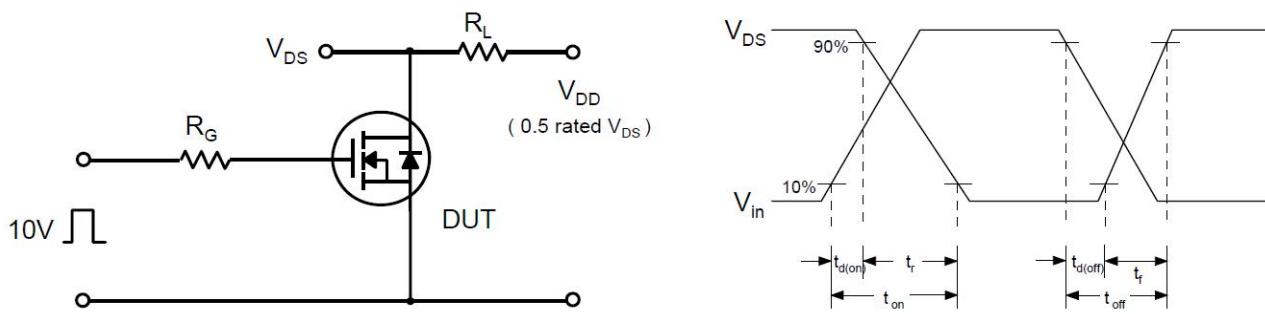


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

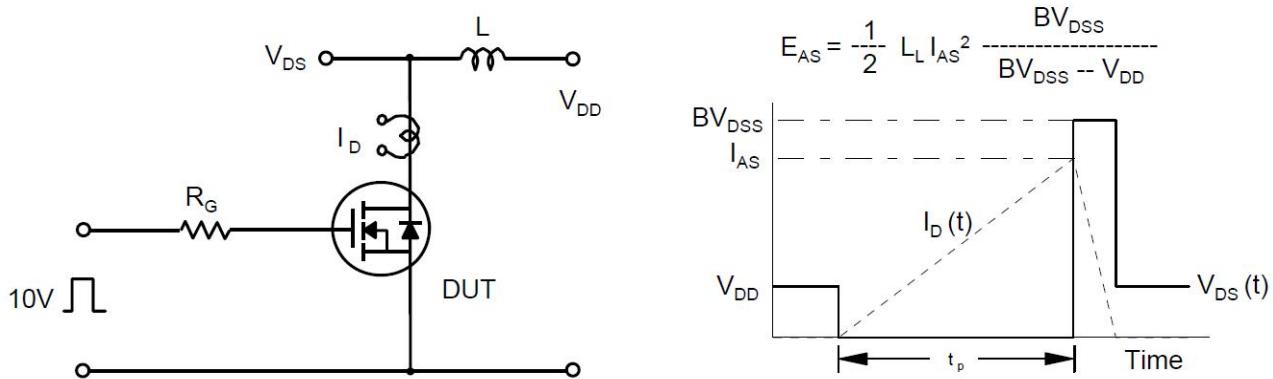
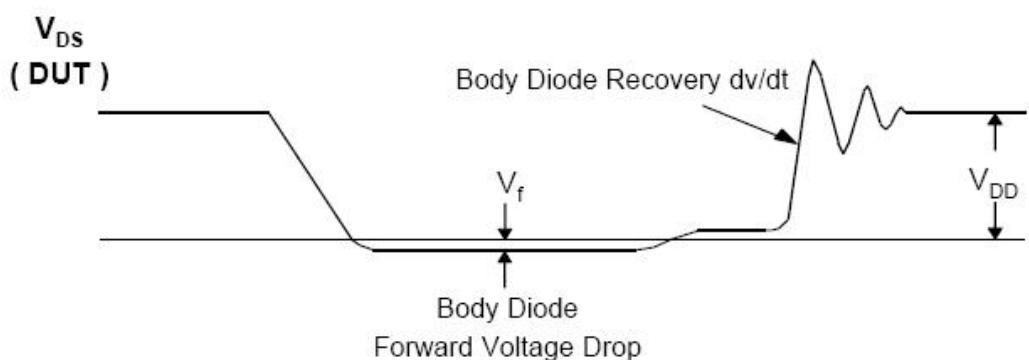
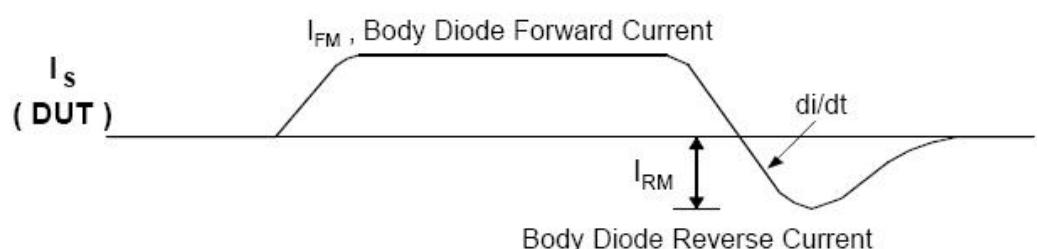
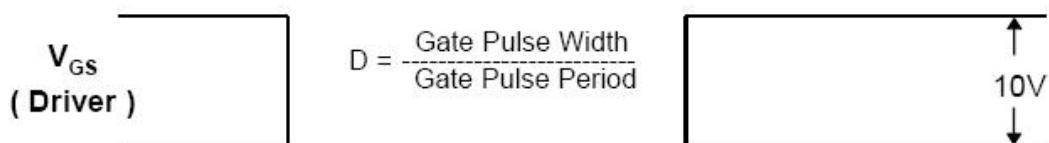
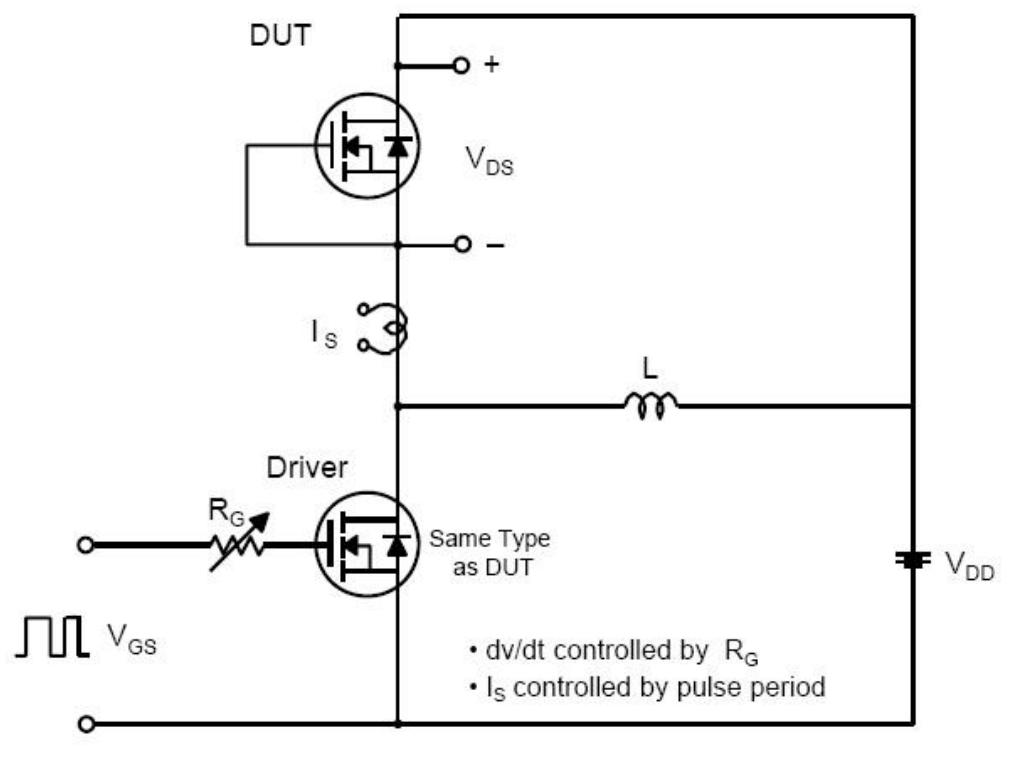
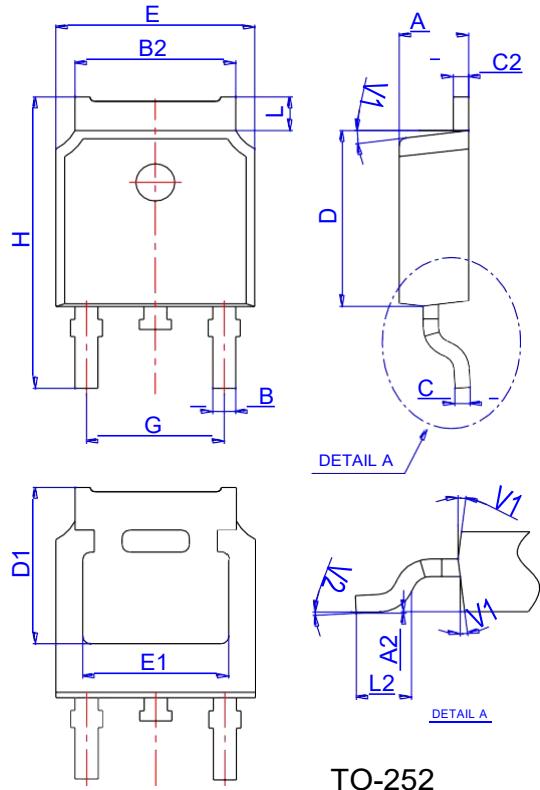


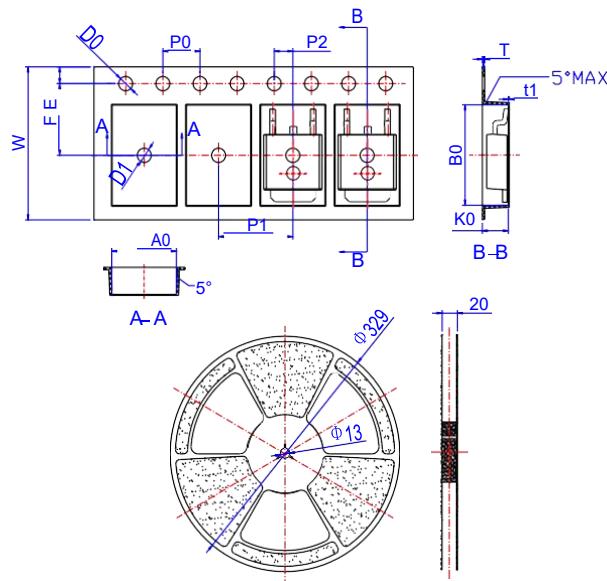
Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



Package Mechanical Data-TO-252-JQ Single


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

TO-252

Reel Specification-TO-252


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	6.85	6.90	7.00	0.270	0.271	0.276
B0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.105	0.109	0.113
T	0.24		0.27	0.009		0.011
t1	0.10			0.004		
10P0	39.80	40.00	40.20	1.567	1.575	1.583